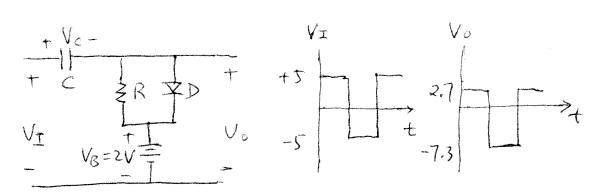


$$V_{\perp} > V_{z,+} V_{y}$$
, Dion Dz off $V_{o} = V_{z,+} V_{y} = 10.7 V$
 $V_{\perp} < -(V_{zz} + V_{y})$, Dioff Dz on $V_{o} = -(V_{zz} + V_{y}) = -20.7 V$
 $-(V_{zz} + V_{y}) < V_{\perp} < V_{z,+} + V_{y}$ Dioff Dz off $V_{o} = V_{\perp}$

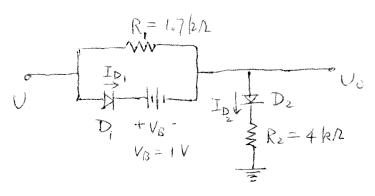
P4



Let capacitor initially discharged $U_c(0) = 0$ When $U_I > V_B + V_Y$ diode is on, capacitor is charging $U_C = V_I - (V_B + V_Y)$ $U_{C,max} = U_{I,max} - (V_B + V_Y) = 5 - 2.7 = 2.3 V$

When $V_{\perp} < V_{\perp}$, max, diode is off. Capacitor discharges very $V_{c} \simeq V_{c}$, max

$$U_0 = V_{\perp} - V_{C,max} = U_{\perp} - 2.3 V$$



If both D1 and D2 are on

$$U_0 = U_{I} - V_{S} - V_{B} = 5 - 0.7 - 1 = 3.3 \text{ V}$$

$$I_{R_1} = \frac{V_{I} - V_{0}}{R_1} = \frac{5 - 3.3}{1.7 \text{ kg}} = 1 \text{ mA}$$

$$I_{D_2} = \frac{V_0 - V_y}{R_2} = \frac{3.3 - 0.7}{4 \, \text{kn}} = 0.65 \, \text{mA}$$

IDI = IDZ - IRI = 0.65 - 1 = -0.35 mA must be of.

Di off, Dzon

$$I_{D_i} = 0$$

$$I_{D2} = I_{R2} = \frac{V_{I} - V_{f}}{R_{i} + R_{2}} = \frac{5 - 0.7}{(1.7 + 4) \text{ kg}} = 0.754 \text{ mA}$$

$$U_0 = V_8 + I_{D2}R_2 = 0.7 + 0.754 \times 4 = 3.72 \text{ V}$$

CMPE 314 Midterm Exam I Solutions

PI

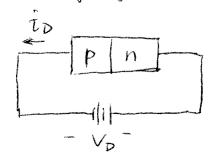
(a) Dope acceptor impurity (group III)

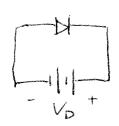
$$p_o = N_a = 7 \times 10^{15} \frac{1}{\text{cm}^3}$$

$$n_o = \frac{n^2}{p_o} = \frac{(1.5 \times 10^{10})^2}{7 \times 10^{15}} = 3.2 \times 10^4 \frac{1}{\text{cm}^3}$$

Holes are majority carriers. Electron are minority carriers.

(b)





ip is due to minority carriers swept by the space-charge field (electrons from p-region and holes from the n-region).

P2

In forward bias

$$I_{D}=I_{s}\left(e^{V_{D}/V_{T}}-1\right)$$

$$\simeq I_{s}e^{V_{D}/V_{T}}$$

Uo = IDR = IsRe

$$U_D = V_T lm(\frac{V_0}{I_s R})$$

$$U_0 = V_I - V_D = V_I - V_T ln\left(\frac{V_0}{I_S R}\right)$$